HVC321B

Variable Capacitance Diode for ET tuner

HITACHI

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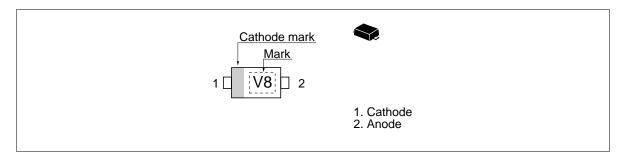
Features

- Low voltage type (tuning voltage 1 to 10V), it is suitable for ET without DC/DC converter.
- High capacitance ratio. (n = 10.5 min)
- Low series resistance. (rs = 1.0 Ω max) and good C-V linearity.
- <u>Ultra small Flat Package</u> (UFP) is suitable for surface mount design.

Ordering Information

Type No.	Laser Mark	Package Code
HVC321B	V8	UFP

Outline





HVC321B

Absolute Maximum Ratings (Ta = 25°C)

Item	Symbol	Value	Unit
Reverse voltage	V_R	15	V
Junction temperature	Tj	125	°C
Storage temperature	Tstg	-55 to +125	°C

Electrical Characteristics ($Ta = 25^{\circ}C$)

Item	Symbol	Min	Тур	Max	Unit	Test Condition
Reverse current	I _{R1}	_	_	10	nA	V _R = 15V
	I _{R2}	_	_	100		V _R = 15V, Ta= 60°C
Capacitance	C ₁	29.0	_	33.0	pF	V _R = 1V, f = 1MHz
	C ₁₀	2.55	_	2.90		V _R = 10V, f = 1MHz
Capacitance ratio	n	10.5	_	_	_	C ₁ /C ₁₀
Series resistance	r _s	_	_	1.0	Ω	V _R = 5V, f = 470MHz
Matching error	ΔC/C*1	_	_	2.0	%	V _R = 1 to 10V, f = 1 MHz

Note 1. C.C system (Continuous Connected taping system) enable to make any 10 pcs of Δ C/C continuous in a reel , expect extention to another group. Calculate Matching Error,

$$\Delta \text{C/C=} \frac{\text{(Cmax-Cmin)}}{\text{Cmin}} \times 100 \text{ (\%)}$$

Main Characteristic

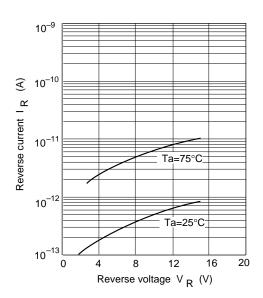


Fig.1 Reverse current Vs. Reverse voltage

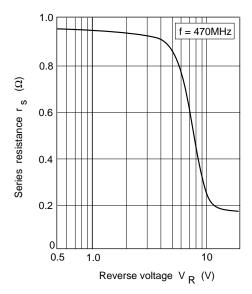


Fig.3 Series resistance Vs. Reverse voltage

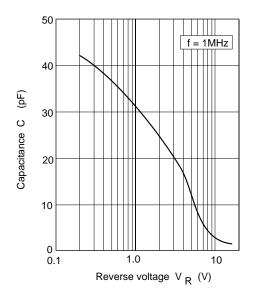
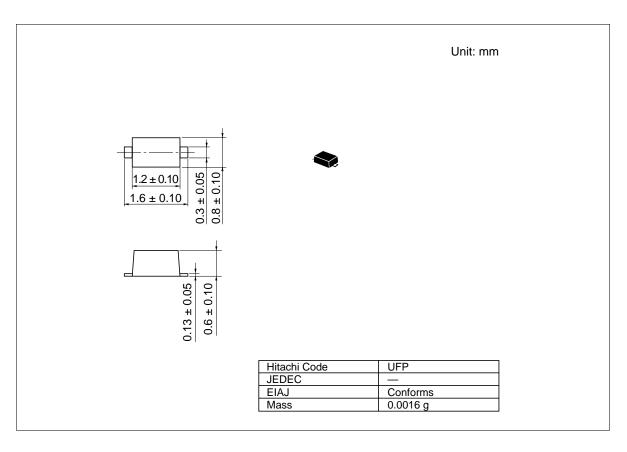


Fig.2 Capacitance Vs. Reverse voltage

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Package Dimensions



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